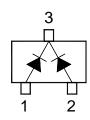
## SILICON EPITAXIAL PLANAR SCHOTTKY BARRIER DIODE





SOT-323 Plastic Package

Marking Code: B7

## Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Value	Unit	
Maximum Peak Reverse Voltage	$V_{RM}$	15	V	
Reverse Voltage	$V_R$	10	V	
Maximum Peak Forward Current	I <sub>FM</sub>	200	mA	
Surge Forward Current (10 ms)	I <sub>FSM</sub>	1	А	
Average Forward Current	Io	100	mA	
Power Dissipation	P <sub>tot</sub>	100	mW	
Junction Temperature	T <sub>j</sub>	125	°C	
Storage Temperature Range	T <sub>s</sub>	-55 to +125	°C	
Operating Temperature Range	T <sub>opr</sub>	-40 to +100	°C	

## Characteristics at $T_a = 25$ °C

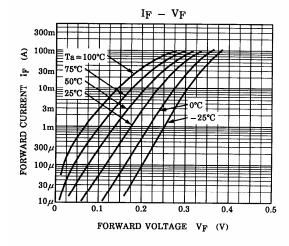
Parameter	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage					
at I <sub>F</sub> = 5 mA	$V_{F}$	-	-	0.3	V
at I <sub>F</sub> = 100 mA		-	-	0.5	
Reverse Current	I_	_	-	20	μA
at $V_R = 10 \text{ V}$	I <sub>R</sub>	_	-	20	μΛ
Total Capacitance	C <sub>⊤</sub>	_	20	40	pF
at $V_R = 0 V$ , $f = 1 MHz$	C <sub>T</sub>	-	20	40	PΓ

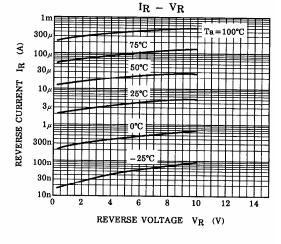


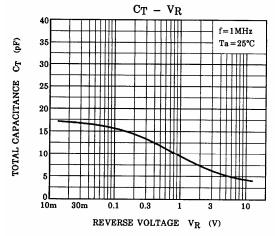


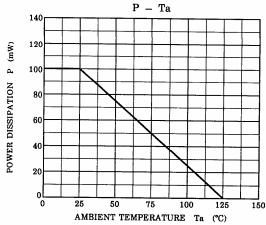
















(Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)







Dated: 27/02/2006